



## JX007V 0.8A Sensitive SCR

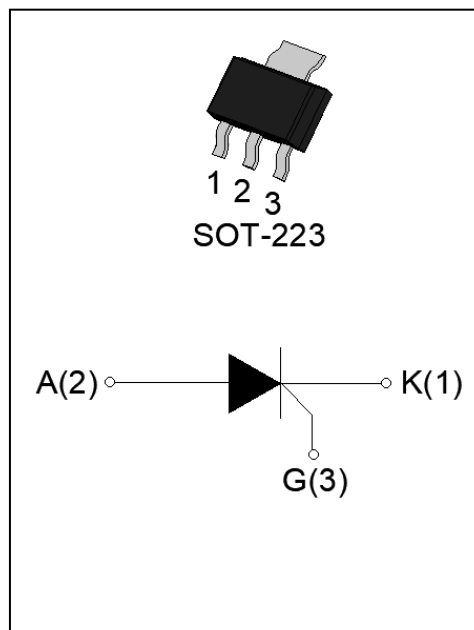
Rev.A.1.0

### DESCRIPTION:

The JX007V SCR provides high dV/dt rate with strong resistance to electromagnetic interface. It is especially recommended for use on residual current circuit breaker, straight hair, igniter etc. Package SOT-223 is RoHS compliant.

### MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	0.8	A
$V_{DRM} / V_{RRM}$	500	V
$I_{GT}$	$\leq 120$	$\mu A$



### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	$^{\circ}C$
Operating junction temperature range	$T_j$	-40-125 <sup>①</sup>	$^{\circ}C$
Repetitive peak off-state voltage ( $T_j=25^{\circ}C$ )	$V_{DRM}$	500	V
Repetitive peak reverse voltage ( $T_j=25^{\circ}C$ )	$V_{RRM}$	500	V
Average on-state current ( $T_c \leq 85^{\circ}C$ )	$I_{T(AV)}$	0.5	A
RMS on-state current ( $T_c \leq 85^{\circ}C$ )	$I_{T(RMS)}$	0.8	A
Non repetitive surge peak on-state current ( $t_p=10ms, T_j=25^{\circ}C$ )	$I_{TSM}$	8	A
Non repetitive surge peak on-state current ( $t_p=8.3ms, T_j=25^{\circ}C$ )		9	
$I^2t$ value for fusing ( $t_p=10ms, T_j=25^{\circ}C$ )	$I^2t$	0.32	$A^2s$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}, f=100Hz, T_j=125^{\circ}C$ )	$di/dt$	50	$A/\mu s$
Peak gate current ( $t_p=20\mu s, T_j=125^{\circ}C$ )	$I_{GM}$	1	A
Average gate power dissipation ( $T_j=125^{\circ}C$ )	$P_{G(AV)}$	0.1	W

Peak gate power	$P_{GM}$	2	W
Peak pulse voltage ( $T_j=25^{\circ}\text{C}$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	1	kV

**NOTE 1:** When we parallel connect a  $\leq 1\text{K}\Omega$  resistor between Gate and Cathode, the  $T_j$  can reach  $125^{\circ}\text{C}$ ; if without this resistor, the  $T_j$  only can reach  $110^{\circ}\text{C}$ .

### ELECTRICAL CHARACTERISTICS ( $T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12\text{V } R_L=33\Omega$	-	-	120	$\mu\text{A}$
$V_{GT}$		-	0.6	0.8	V
$V_{GD}$	$V_D=V_{DRM} T_j=125^{\circ}\text{C}$	0.2	-	-	V
$I_L$	$I_G=1.2 I_{GT}$	-	-	5	mA
$I_H$	$I_T=0.05\text{A}$	-	-	3	mA
dV/dt	$V_D=335\text{V } T_j=125^{\circ}\text{C } R_{GK}=1\text{K}\Omega$	20	-	-	$\text{V}/\mu\text{s}$
	$V_D=335\text{V } T_j=125^{\circ}\text{C } R_{GK}=220\Omega$	50	-	-	
$t_{on}$	$I_G=10\text{mA } I_A=20\text{mA } I_R=2\text{mA}$	-	2	-	$\mu\text{s}$
$t_{off}$	$T_j=25^{\circ}\text{C}$	-	50	-	$\mu\text{s}$

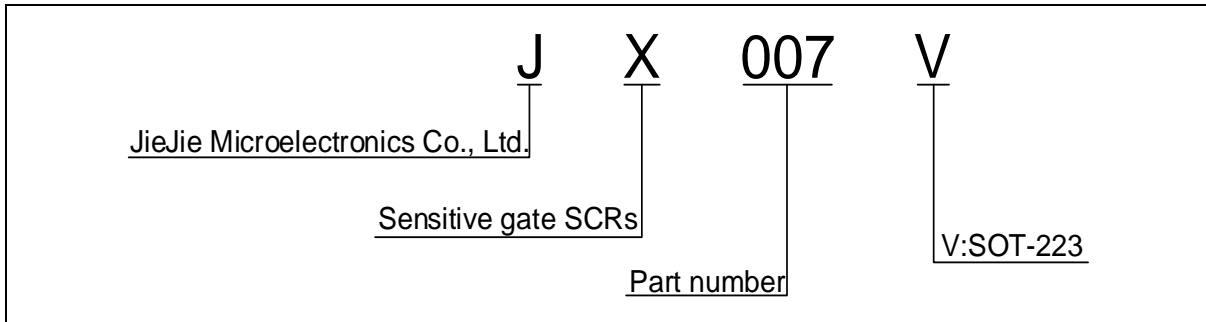
### STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_T=1\text{A } t_p=380\mu\text{s}$	$T_j=25^{\circ}\text{C}$	1.3	V
$V_{TO}$	Threshold voltage	$T_j=125^{\circ}\text{C}$	0.9	V
$R_D$	Dynamic Resistance	$T_j=125^{\circ}\text{C}$	0.3	$\Omega$
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^{\circ}\text{C}$	1	$\mu\text{A}$
$I_{RRM}$		$T_j=125^{\circ}\text{C}$	0.1	mA

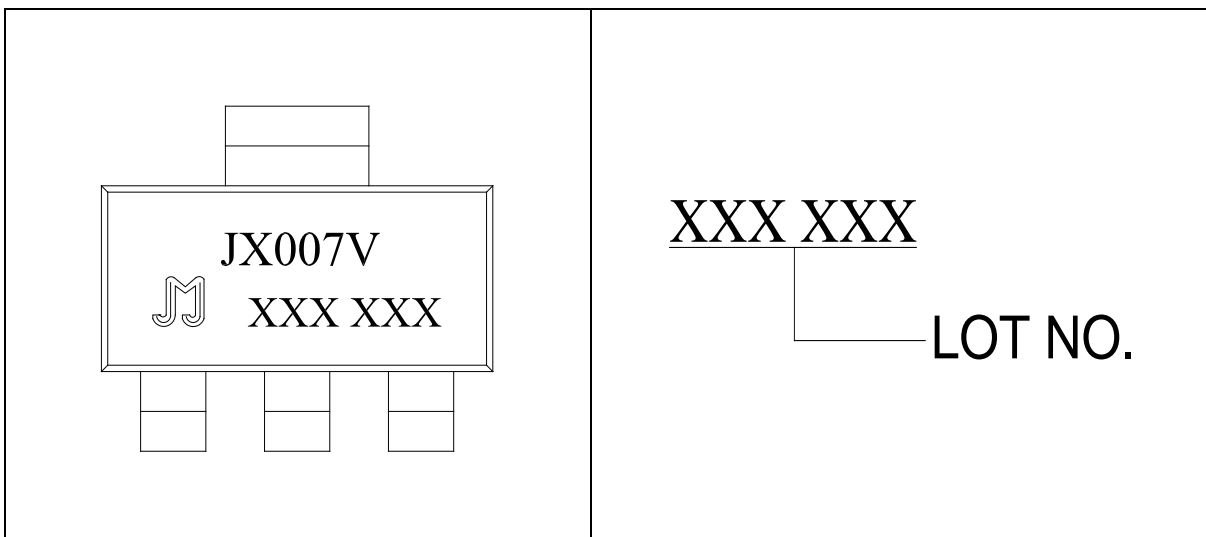
### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (DC)	40	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient (DC)	120	$^{\circ}\text{C}/\text{W}$

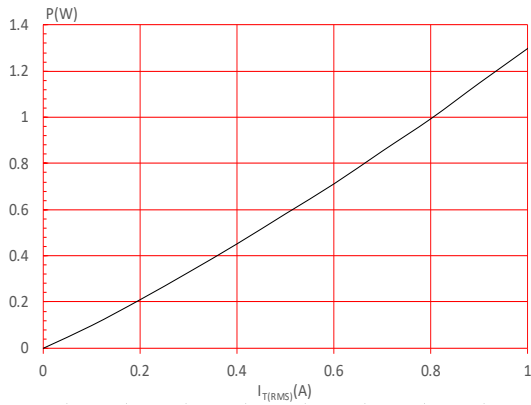
**ORDERING INFORMATION**



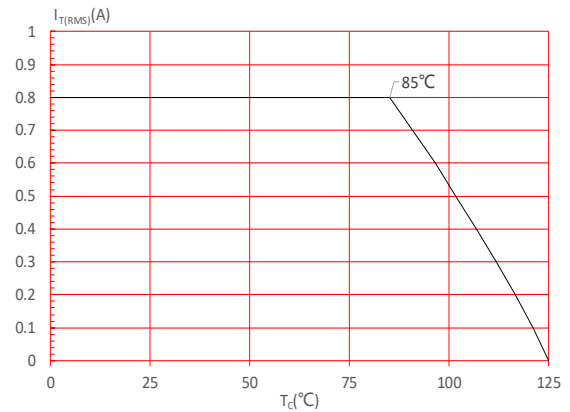
**MARKING**



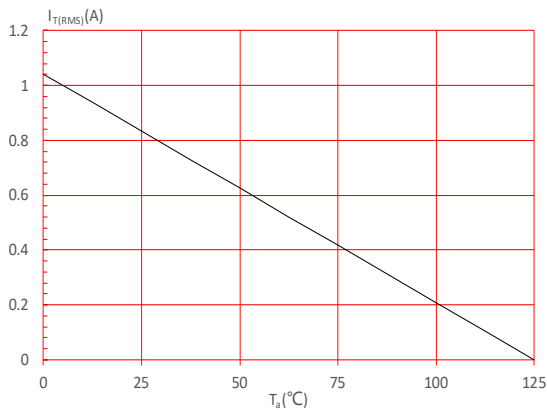
**FIG.1** Maximum power dissipation versus RMS on-state current



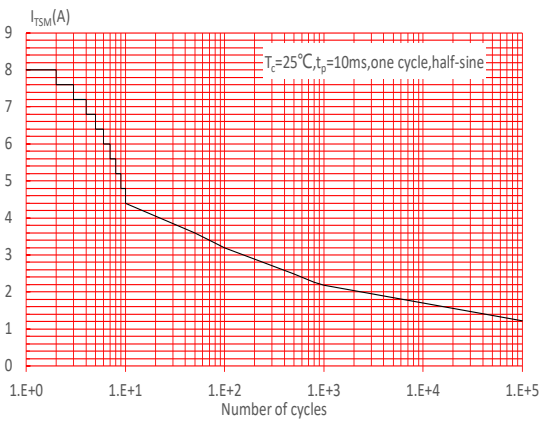
**FIG.2:** RMS on-state current versus case temperature



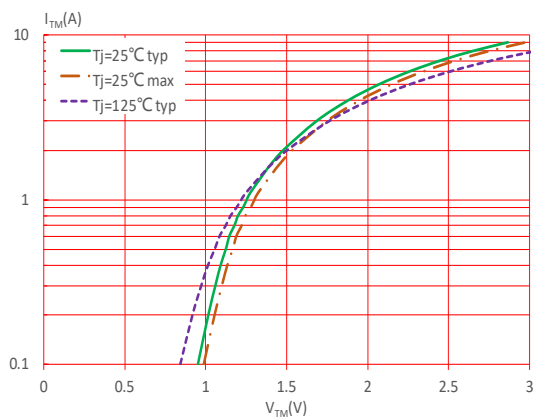
**FIG.3:** RMS on-state current versus ambient temperature (printed circuit board FR4,copper thickness:35μm)(full cycle)



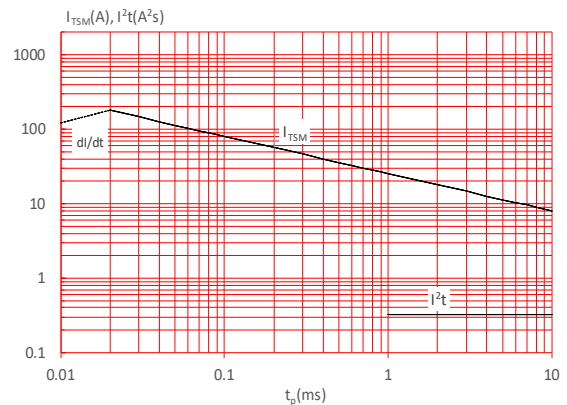
**FIG.4:** Surge peak on-state current versus number of cycles



**FIG.5:** On-state characteristics



**FIG.6:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $di/dt < 50\text{A}/\mu\text{s}$ )



**FIG.7:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

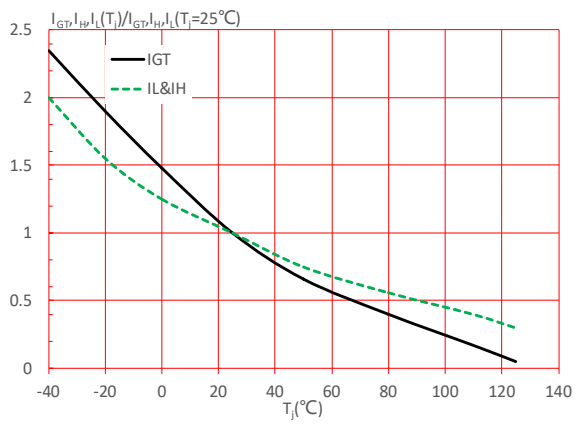
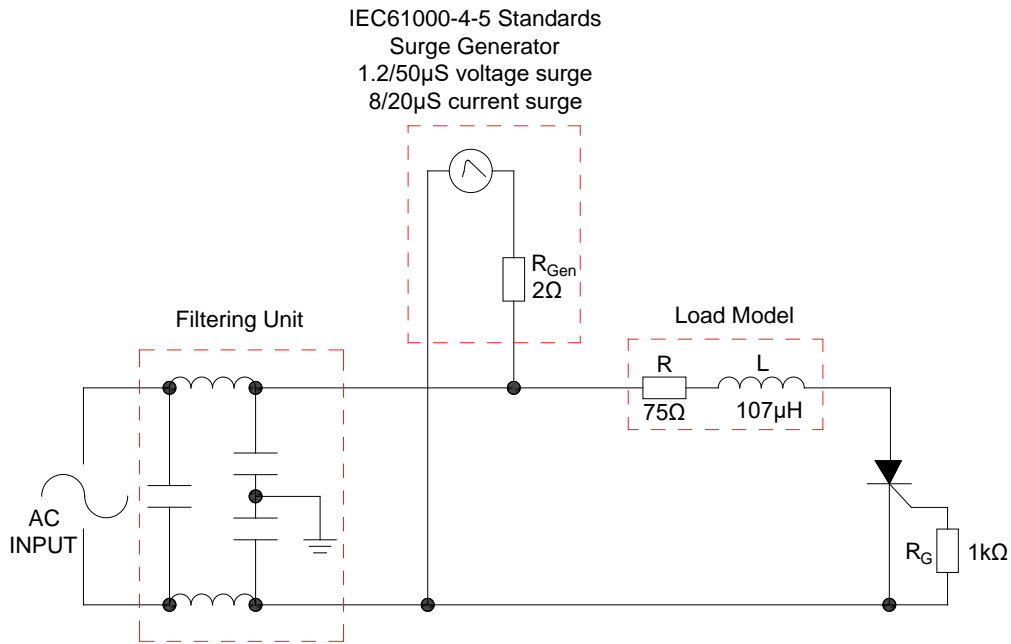
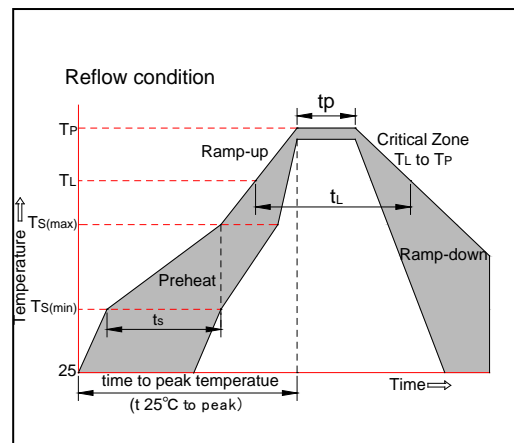


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



**SOLDERING PARAMETERS**

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150°C
	-Temperature Max ( $T_{s(max)}$ )	+200°C
	-Time (Min to Max) ( $t_s$ )	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3°C/sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature( $T_L$ ) (Liquidus)	+217°C
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)°C
Time within 5°C of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp ( $T_p$ )		8 min. Max
Do not exceed		+260°C



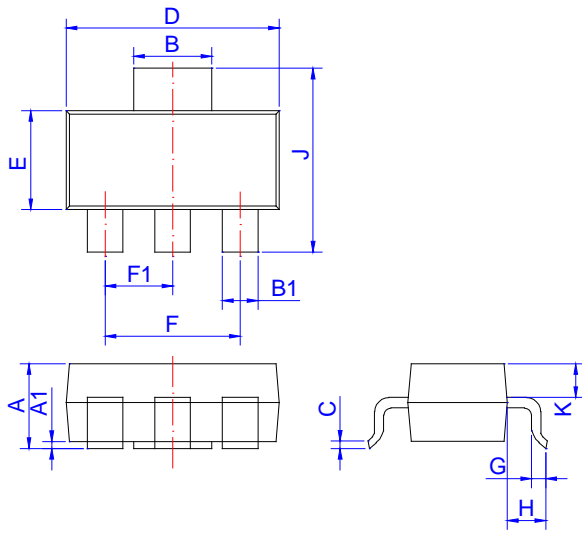
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT( $\mu$ A)	Package	Base qty. (pcs)	Delivery mode
JX007V	500	$\leq 120$	SOT-223	4,000	Tape & Reel

**Document Revision History**

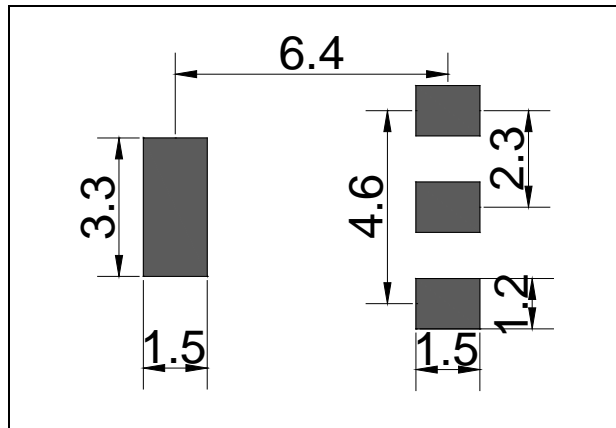
Date	Revision	Changes
Apr.12, 2023	A.1.0	Last update

**PACKAGE MECHANICAL DATA**



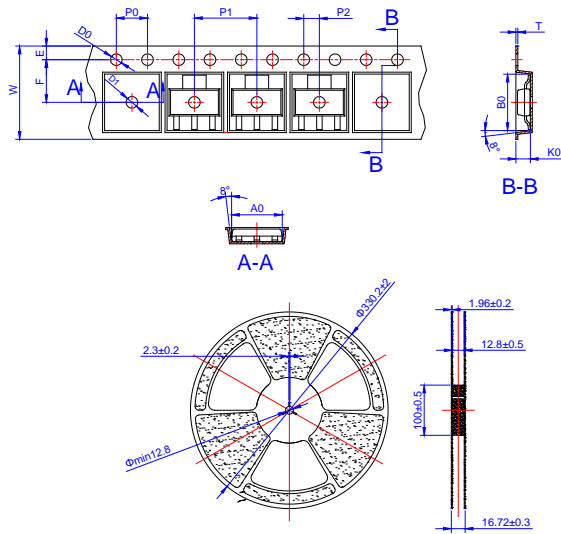
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.5	1.6	1.8	0.059	0.063	0.071
A1	0.01	0.06	0.10	0.001	0.002	0.004
B	2.9	3.0	3.1	0.114	0.118	0.122
B1	0.6	0.7	0.8	0.024	0.028	0.031
C	0.22	0.26	0.32	0.009	0.010	0.013
D	6.3	6.5	6.7	0.248	0.256	0.264
E	3.3	3.5	3.7	0.130	0.138	0.146
F	4.4		4.8	0.173		0.189
F1	2.2		2.4	0.087		0.094
G	0.5		1.0	0.020		0.039
H	1.5	1.75	2.0	0.059	0.069	0.079
J	6.7	7.0	7.3	0.264	0.276	0.287
K	0.8	0.9	1.0	0.031	0.035	0.039

**FOOTPRINT-SOT-223 (dimensions in mm)**






DELIVERY MODE



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	-	-	12.30	-	-	0.482
E	1.65	1.75	1.85	0.065	0.069	0.073
F	5.45	5.50	5.55	0.215	0.217	0.219
D0	1.50	1.55	1.60	0.059	0.061	0.063
D1	1.50	-	-	0.059	-	-
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.95	2.00	2.05	0.077	0.079	0.081
10P0	39.80	40.00	40.20	1.567	1.575	1.583
A0	6.85	6.95	7.05	0.269	0.273	0.276
B0	7.15	7.25	7.35	0.280	0.284	0.288
K0	1.95	2.05	2.15	0.076	0.080	0.084
T	0.20	0.25	0.30	0.008	0.010	0.012

PACKAGE	OUTLINE	REEL (PCS)	PER CARTON (PCS)	TAPE & REEL
SOT-223	TAPING	4,000	40,000	13 inch

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